

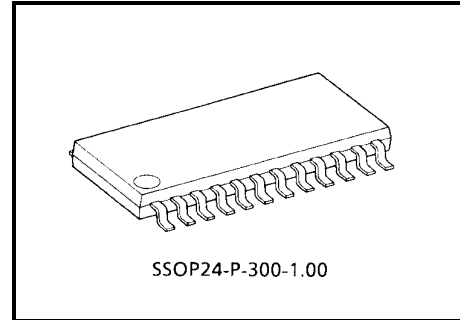
TOSHIBA Bi-CMOS Integrated Circuit Silicon Monolithic

TB6551F/FG

3-PHASE FULL-WAVE SINE-WAVE PWM BRUSHLESS MOTOR CONTROLLER

Features

- Sine-wave PWM control
- Built-in triangular-wave generator
(carrier cycle = $f_{osc}/252$ (Hz))
- Built-in lead angle control function (0° to 58° in 32 steps)
- Built-in dead time function (setting 2.6 μ s or 3.8 μ s)
- Over-current protection signal input pin
- Built-in regulator ($V_{ref} = 5$ V (typ.), 30 mA (max))
- Operating supply voltage range: $V_{CC} = 6$ V to 10 V



Weight: 0.33 g (typ.)

TB6551FG:

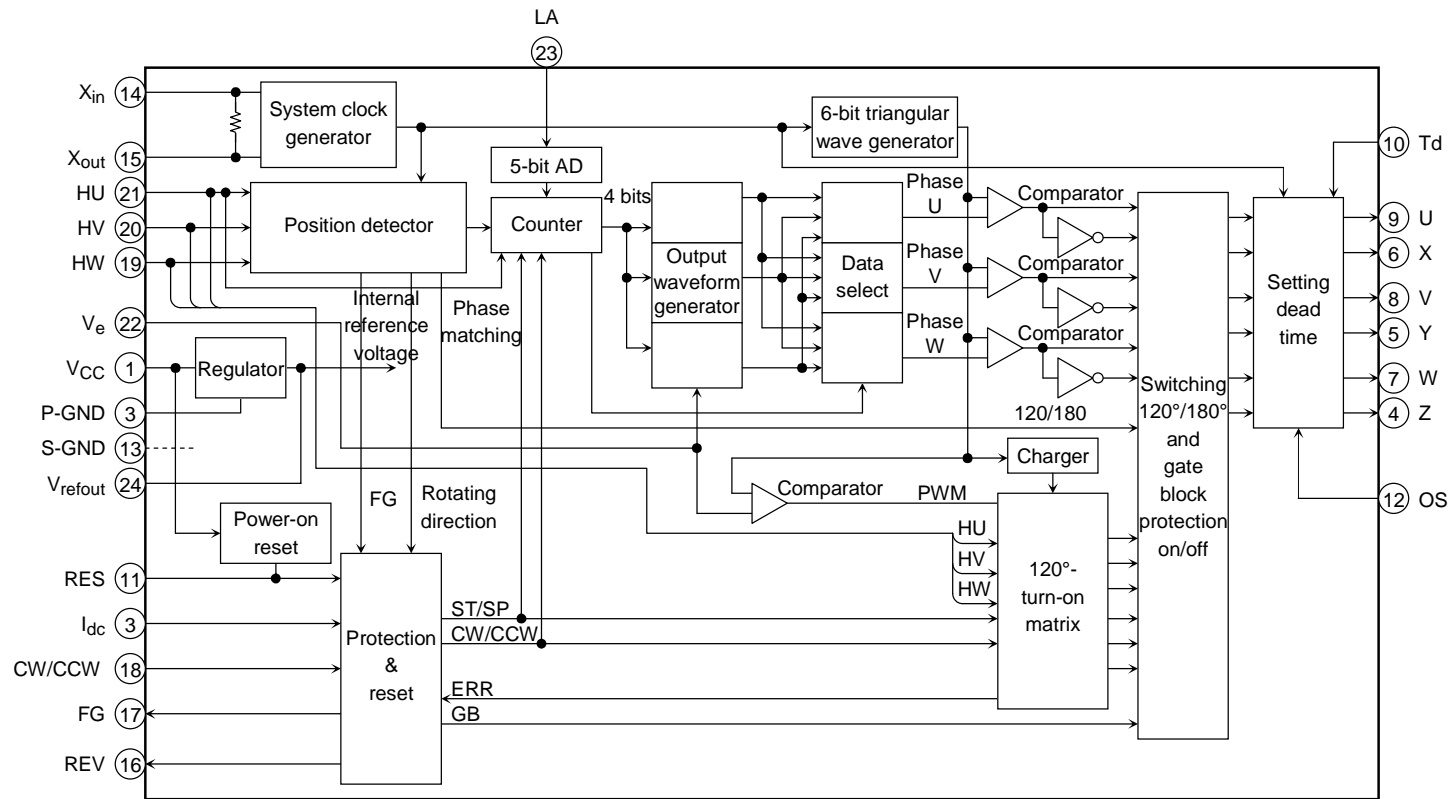
The TB6551FG is a Pb-free product.

The following conditions apply to solderability:

*Solderability

1. Use of Sn-37Pb solder bath
 - *solder bath temperature = 230°C
 - *dipping time = 5 seconds
 - *number of times = once
 - *use of R-type flux
2. Use of Sn-3.0Ag-0.5Cu solder bath
 - *solder bath temperature = 245°C
 - *dipping time = 5 seconds
 - *number of times = once
 - *use of R-type flux

Block Diagram



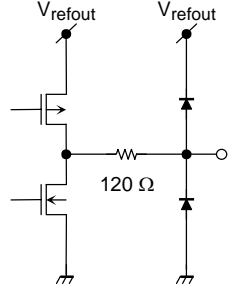
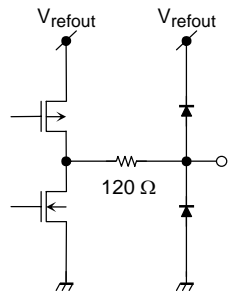
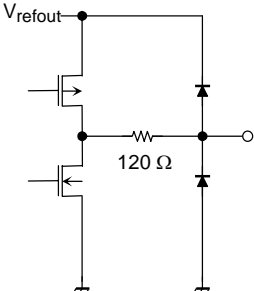
Pin Description

| Pin No. | Symbol | Description | Remarks |
|---------|---------------------|---------------------------------------|---|
| 21 | HU | Positional signal input pin U | When positional signal is HHH or LLL, gate block protection operates. With built-in pull-up resistor |
| 20 | HV | Positional signal input pin V | |
| 19 | HW | Positional signal input pin W | |
| 18 | CW/CCW | Rotation direction signal input pin | L: Forward H: Reverse |
| 11 | RES | Reset-signal-input pin | L: Reset (output is non-active) Operation/Halt operation Also used for gate block protection |
| 22 | V _e | Inputs voltage instruction signal | With built-in pull-down resistor |
| 23 | LA | Lead angle setting signal input pin | Sets 0° to 58° in 32 steps |
| 12 | OS | Inputs output logic select signal | L: Active low H: Active high |
| 3 | I _{dc} | Inputs over-current-protection-signal | Inputs DC link current. Reference voltage: 0.5 V With built-in filter (≈ 1 μs) |
| 14 | X _{in} | Inputs clock signal | With built-in feedback resistor |
| 15 | X _{out} | Outputs clock signal | |
| 24 | V _{refout} | Outputs reference voltage signal | 5 V (typ.), 30 mA (max) |
| 17 | FG | FG signal output pin | Outputs 3PPR of positional signal |
| 16 | REV | Reverse rotation detection signal | Detects reverse rotation. |
| 9 | U | Outputs turn-on signal | Select active high or active low using the output logic select pin. |
| 8 | V | Outputs turn-on signal | |
| 7 | W | Outputs turn-on signal | |
| 6 | X | Outputs turn-on signal | |
| 5 | Y | Outputs turn-on signal | |
| 4 | Z | Outputs turn-on signal | |
| 1 | V _{CC} | Power supply voltage pin | V _{CC} = 6 V~10 V |
| 10 | T _d | Inputs setting dead time | L: 3.8 μs, H or Open: 2.6 μs |
| 2 | P-GND | Ground for power supply | Ground pin |
| 13 | S-GND | Ground for signals | Ground pin |

Input/Output Equivalent Circuits

| Pin Description | Symbol | Input/Output Signal | Input/Output Internal Circuit |
|---|--------|---|-------------------------------|
| Positional signal input pin U | HU | Digital | |
| Positional signal input pin V | HV | With Schmitt trigger Hysteresis 300 mV (typ.) | |
| Positional signal input pin W | HW | L: 0.8 V (max) H: $V_{refout} - 1$ V (min) | |
| Forward/reverse switching input pin | CW/CCW | Digital | |
| L: Forward (CW) H: Reverse (CCW) | | With Schmitt trigger Hysteresis 300 mV (typ.) L: 0.8 V (max) H: $V_{refout} - 1$ V (min) | |
| Reset input | RES | Digital | |
| L: Stops operation (reset). H: Operates. | | With Schmitt trigger Hysteresis 300 mV (typ.) L: 0.8 V (max) H: $V_{refout} - 1$ V (min) | |
| Voltage instruction signal input pin | V_e | Analog | |
| Turn on the lower transistor at 0.2 V or less. (X, Y, Z pins: On duty of 8%) | | Input range 0 V to 5.0 V Input voltage of V_{refout} or higher is clipped to V_{refout} . | |
| Lead angle setting signal input pin | LA | Analog | |
| 0 V: 0° 5 V: 58° (5-bit AD) | | Input range 0 V to 5.0 V Input voltage of V_{refout} or higher is clipped to V_{refout} . | |

| Pin Description | Symbol | Input/Output Signal | Input/Output Internal Circuit |
|---|---------------------|---|-------------------------------|
| Setting dead time input pin L: 3.8 μ s H or Open: 2.6 μ s | Td | Digital L: 0.8 V (max) H: $V_{refout} - 1$ V (min) | |
| Output logic select signal input pin L: Active low H: Active high | OS | Digital L: 0.8 V (max) H: $V_{refout} - 1$ V (min) | |
| Over-current protection signal input pin | I _{dc} | Analog Gate block protected at 0.5 V or higher (released at carrier cycle) | |
| Clock signal input pin | X _{in} | Operating range 2 MHz to 8 MHz (crystal oscillation) | |
| Clock signal output pin | X _{out} | | |
| Reference voltage signal output pin | V _{refout} | 5 ± 0.5 V (max 30 mA) | |

| Pin Description | Symbol | Input/Output Signal | Input/Output Internal Circuit |
|--|----------------------------|---|--|
| Reverse-rotation-detection signal output pin | REV | Digital Push-pull output: ± 1 mA (max) |  |
| FG signal output pin | FG | Digital Push-pull output: ± 1 mA (max) |  |
| Turn-on signal output pin U Turn-on signal output pin V Turn-on signal output pin W Turn-on signal output pin X Turn-on signal output pin Y Turn-on signal output pin Z | U V W X Y Z | Analog Push-pull output: ± 2 mA (max) L: 0.78 V (max) H: $V_{refout} - 0.78$ V (min) |  |

Absolute Maximum Ratings (Ta = 25°C)

| Characteristics | Symbol | Rating | Unit |
|-------------------------------|---------------------|-------------------------------|------|
| Supply voltage | V _{CC} | 12 | V |
| Input voltage | V _{in} (1) | -0.3~V _{CC} (Note 1) | V |
| | V _{in} (2) | -0.3~5.5 (Note 2) | |
| Turn-on signal output current | I _{OUT} | 2 | mA |
| Power Dissipation | P _D | 0.9 (Note 3) | W |
| Operating temperature | T _{opr} | -30~115 (Note 4) | °C |
| Storage temperature | T _{stg} | -50~150 | °C |

Note 1: V_{in} (1) pin: V_e, LA

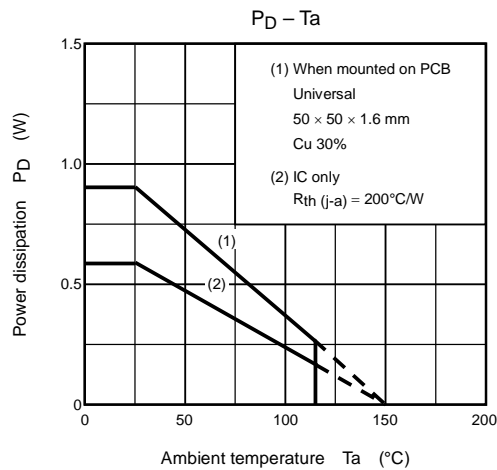
Note 2: V_{in} (2) pin: HU, HV, HW, CW/CCW, RES, OS, I_{dc}, T_d

Note 3: When mounted on a PCB (universal 50 × 50 × 1.6 mm, Cu 30%)

Note 4: Operating temperature range is determined by the P_D – Ta characteristic.

Operating Conditions (Ta = 25°C)

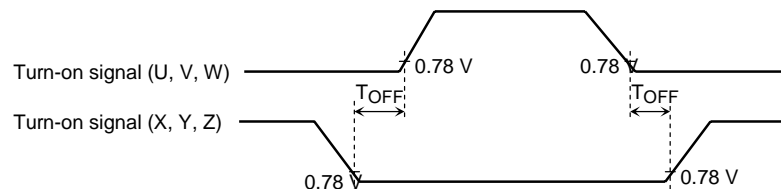
| Characteristics | Symbol | Min | Typ. | Max | Unit |
|-------------------------------|-----------------|-----|------|-----|------|
| Supply voltage | V _{CC} | 6 | 7 | 10 | V |
| Crystal oscillation frequency | X _{in} | 2 | 4 | 8 | MHz |



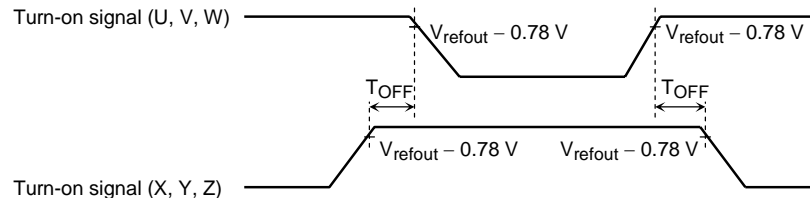
Electrical Characteristics (Ta = 25°C, VCC = 7 V)

| Characteristics | Symbol | Test Circuit | Test Condition | Min | Typ. | Max | Unit |
|---|------------------------|--------------|---|----------------------------|---------------------------|---------------------|------|
| Supply current | I _{CC} | — | V _{refout} = open | — | 3 | 6 | mA |
| Input current | I _{in} (1) | — | V _{in} = 5 V V _e , LA | — | 20 | 40 | μA |
| | I _{in} (2)-1 | | V _{in} = 0 V HU, HV, HW | -40 | -20 | — | |
| | I _{in} (2)-2 | | V _{in} = 0 V CW/CCW, OS, Td | -80 | -40 | — | |
| | I _{in} (2)-3 | | V _{in} = 5 V RES | — | 40 | 80 | |
| Input voltage | V _{in} | High | HU, HV, HW, CW/CCW, RES, OS, Td | V _{refout} - 1 | — | V _{refout} | V |
| | | Low | | — | — | 0.8 | |
| Input hysteresis voltage | V _H | — | HU, HV, HW, CW/CCW, RES | — | 0.3 | — | V |
| Output voltage | V _{OUT} (H)-1 | — | I _{OUT} = 2 mA U, V, W, X, Y, Z | V _{refout} - 0.78 | V _{refout} - 0.4 | — | V |
| | V _{OUT} (L)-1 | | I _{OUT} = -2 mA U, V, W, X, Y, Z | — | 0.4 | 0.78 | |
| | V _{REV} (H) | | I _{OUT} = 1 mA REV | V _{refout} - 1.0 | V _{refout} - 0.5 | — | |
| | V _{REV} (L) | | I _{OUT} = -1 mA REV | — | 0.5 | 1.0 | |
| | V _{FG} (H) | | I _{OUT} = 1 mA FG | V _{refout} - 1.0 | V _{refout} - 0.5 | — | |
| | V _{FG} (L) | | I _{OUT} = -1 mA FG | — | 0.5 | 1.0 | |
| | V _{refout} | | I _{OUT} = 30 mA V _{refout} | 4.5 | 5.0 | 5.5 | |
| Output leakage current | I _L (H) | — | V _{OUT} = 0 V U, V, W, X, Y, Z | — | 0 | 10 | μA |
| | I _L (L) | | V _{OUT} = 3.5 V U, V, W, X, Y, Z | — | 0 | 10 | |
| Output off-time by upper/lower transistor (Note 1) | T _{OFF} (H) | — | Td = High or open, X _{in} = 4.19 MHz, I _{OUT} = ± 2 mA, OS = High/Low | 2.2 | 2.6 | — | μs |
| | T _{OFF} (L) | | Td = Low, X _{in} = 4.19 MHz, I _{OUT} = ± 2 mA, OS = High/Low | 3.0 | 3.8 | — | |
| Over-current detection | V _{dc} | — | I _{dc} | 0.46 | 0.5 | 0.54 | V |
| Lead angle correction | T _{LA} (0) | — | L _A = 0 V or Open, Hall IN = 100 Hz | — | 0 | — | ° |
| | T _{LA} (2.5) | | L _A = 2.5 V, Hall IN = 100 Hz | 27.5 | 32 | 34.5 | |
| | T _{LA} (5) | | L _A = 5 V, Hall IN = 100 Hz | 53.5 | 59 | 62.5 | |
| V _{CC} monitor | V _{CC} (H) | — | Output start operation point | 4.2 | 4.5 | 4.8 | V |
| | V _{CC} (L) | | No output operation point | 3.7 | 4.0 | 4.3 | |
| | V _H | | Input hysteresis width | — | 0.5 | — | |

Note 5: T_{OFF}
OS = High



OS = Low



Functional Description

Basic operation

On start-up, the motor is driven by the square-wave turn-on signal based on a positional signal. When the positional signal reaches number of rotations $f = 5$ Hz or higher, the rotor position is inferred from the positional signal and a modulation wave is generated. The modulation wave and the triangular wave are compared; the sine-wave PWM signal is then generated and the motor is driven.

From start to 5 Hz: When driven by square wave (120° turn-on) $f = f_{osc}/(2^{12} \times 32 \times 6)$
 5 Hz~: When driven by sine-wave PWM (180° turn-on) When $f_{osc} = 4$ MHz, approx. 5 Hz

Function to stabilize bootstrap voltage

- (1) When voltage instruction is input at $V_e \leq 0.2$ V:
The lower transistor is turned on at the regular (carrier) cycle. (On duty is approx. 8%.)
- (2) When voltage instruction is input at $V_e > 0.2$ V:
During sine-wave drive, the drive signal is output as it is.
During square-wave drive, the lower transistor is forcibly turned on at the regular (carrier) cycle. (On duty is approx. 8%.)

Note: At startup, to charge the upper transistor gate power supply, turn the lower transistor on for a fixed time with $V_e \leq 0.2$ V.

Dead time function: upper/lower transistor output off-time

When the motor is driven by a sine-wave PWM, dead time is generated digitally in the IC to prevent any short circuit caused by the simultaneous turning on of upper and lower external power devices.

When a square wave is generated in full duty cycle mode, the dead time function is turned on to prevent a short circuit.

| Td Pin | Internal Counter | T _{OFF} |
|--------------|---------------------|------------------|
| High or Open | 11/f _{osc} | 2.6 μs |
| Low | 16/f _{osc} | 3.8 μs |

T_{OFF} values above are obtained when $f_{osc} = 4.19$ MHz.
 f_{osc} = reference clock (crystal oscillation)

Correcting lead angle

The lead angle can be corrected in the turn-on signal range from 0 to 58° in relation to the induced voltage.

Analog input from LA pin (0 V to 5 V divided by 32):

0 V = 0°

5 V = 58° (when more than 5 V is input, 58°)

Setting carrier frequency

This feature sets the triangular wave cycle (carrier cycle) necessary for generating the PWM signal. (The triangular wave is used for forcibly turning on the lower transistor when the motor is driven by square wave.)

Carrier cycle = $f_{osc}/252$ (Hz)

f_{osc} = Reference clock (crystal oscillation)

Switching the output of turn-on signal

This function switches the output of the turn-on signal between high and low.

Pin OS:

High = active high

Low = active low

Outputting reverse rotation detection signal

The direction of motor rotation is detected for every electrical angle of 360°. (The output is high immediately after reset.)

The REV terminal increases to a 180° turn-on mode at the time of low.

| CW/CCW Pin | Actual Motor Rotating Direction | REV Pin |
|------------|---------------------------------|---------|
| Low (CW) | CW (forward) | Low |
| | CCW (reverse) | High |
| High (CCW) | CW (forward) | High |
| | CCW (reverse) | Low |

Protecting input pin

1. Over-current protection (Pin I_{dc})

When the DC-link-current exceeds the internal reference voltage, gate block protection is performed. Over-current protection is released for each carrier frequency.

Reference voltage = 0.5 V (typ.)

2. Gate block protection (Pin RES)

When the input signal level is Low, the output is turned off; when the signal is High, the output is restarted.

Abnormalities are detected externally, and the signal is input to the pin RES.

| RES Pin | OS Pin | Output Turn-on Signal (U, V, W, X, Y, Z) |
|---------|--------|--|
| Low | Low | High |
| | High | Low |

(When RES = Low, bootstrap capacitor charging stops.)

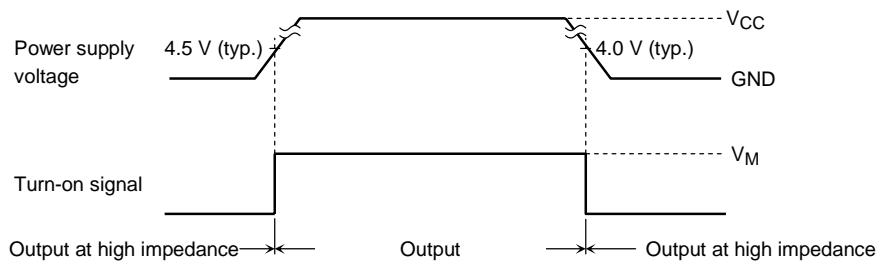
3. Internal protection

• Positional signal abnormality protection

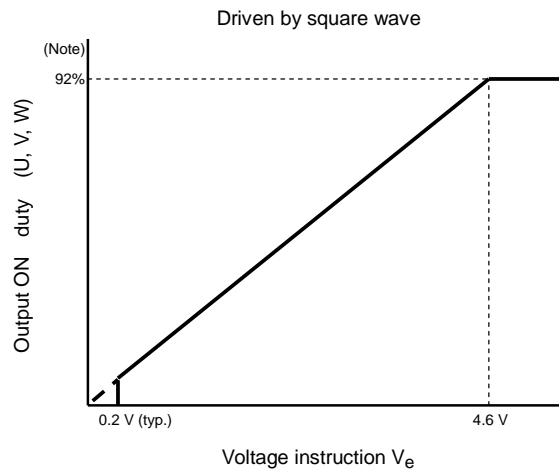
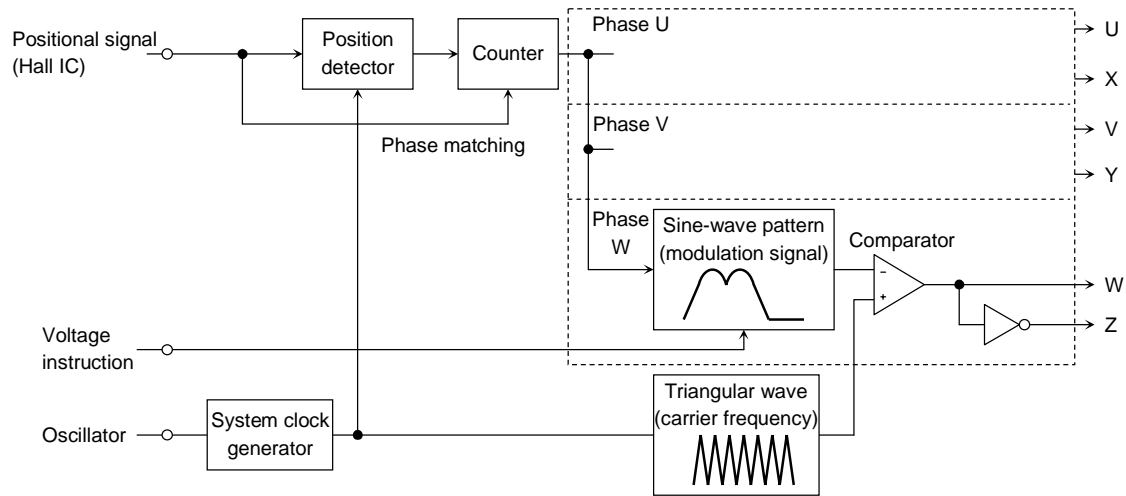
When the positional signal is HHH or LLL, the output is turned off; otherwise, the output is restarted.

• Low power supply voltage protection (V_{CC} monitor)

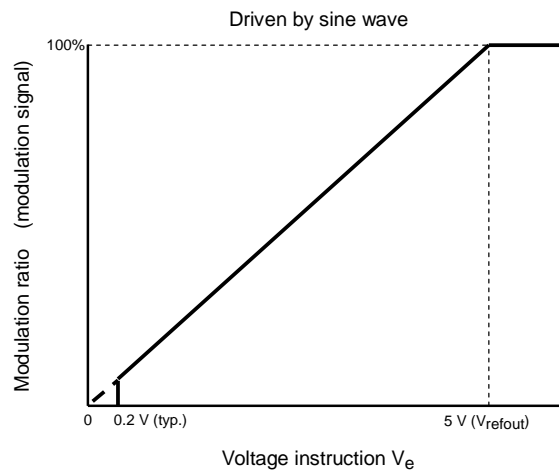
Outside the operating voltage range, the turn-on signal output is kept at high impedance to prevent damage caused by short-circuiting of power components when the power supply is turned on or off.



Operation Flow



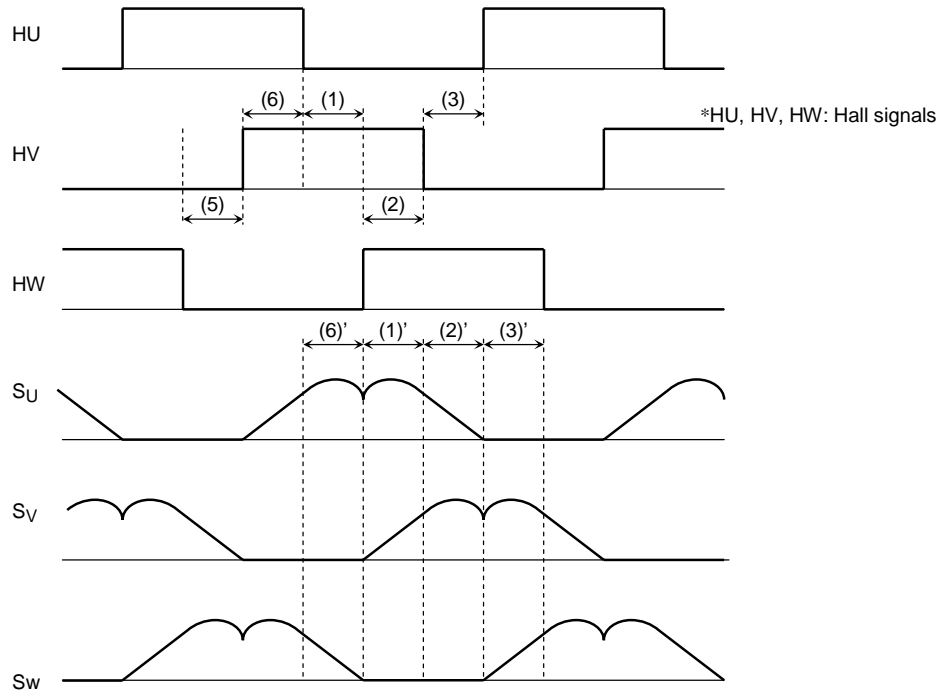
Note: Output ON time is decreased by the dead time (carrier frequency × 92% - T_d × 2).



The modulation waveform is generated using Hall signals. The modulation waveform is then compared with the triangular wave and a sine-wave PWM signal is generated.

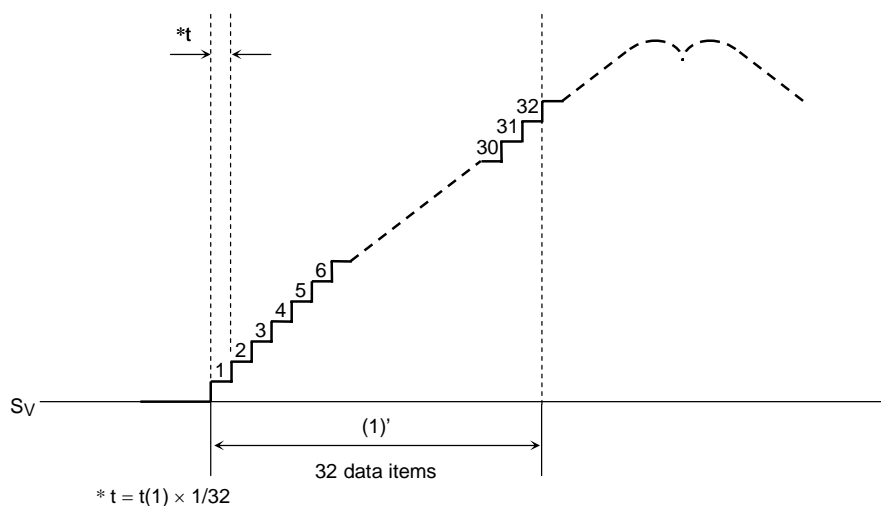
The time (electrical angle: 60°) from the rising (or falling) edges of the three Hall signals to the next falling (or rising) edges is counted. The counted time is used as the data for the next 60° phase of the modulation waveform.

There are 32 items of data for the 60° phase of the modulation waveform. The time width of one data item is 1/32 of the time width of the 60° phase of the previous modulation waveform. The modulation waveform moves forward by this width.



In the above diagram, the modulation waveform (1)' data moves forward by the 1/32 time width of the time (1) from HU: ↑ to HW: ↓. Similarly, data (2)' moves forward by the 1/32 time width of the time (2) from HW: ↓ to HV: ↑.

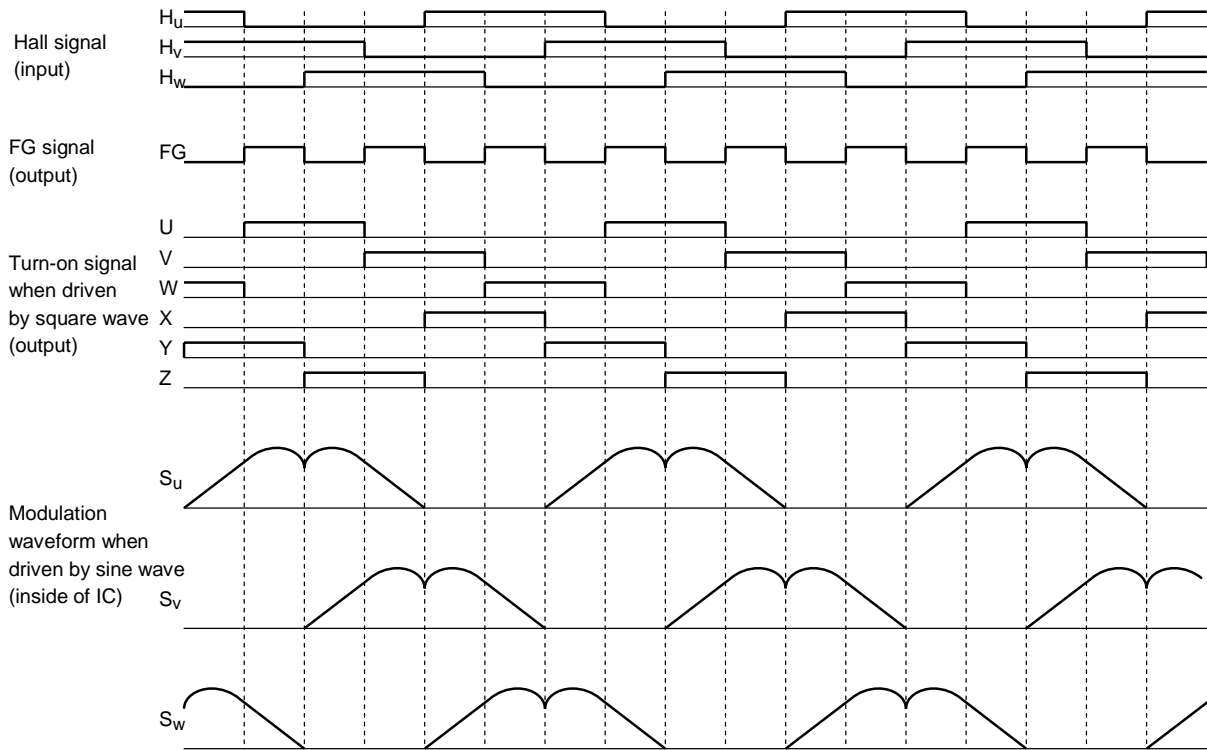
If the next edge does not occur after the 32 data items end, the next 32 data items move forward by the same time width until the next edge occurs.



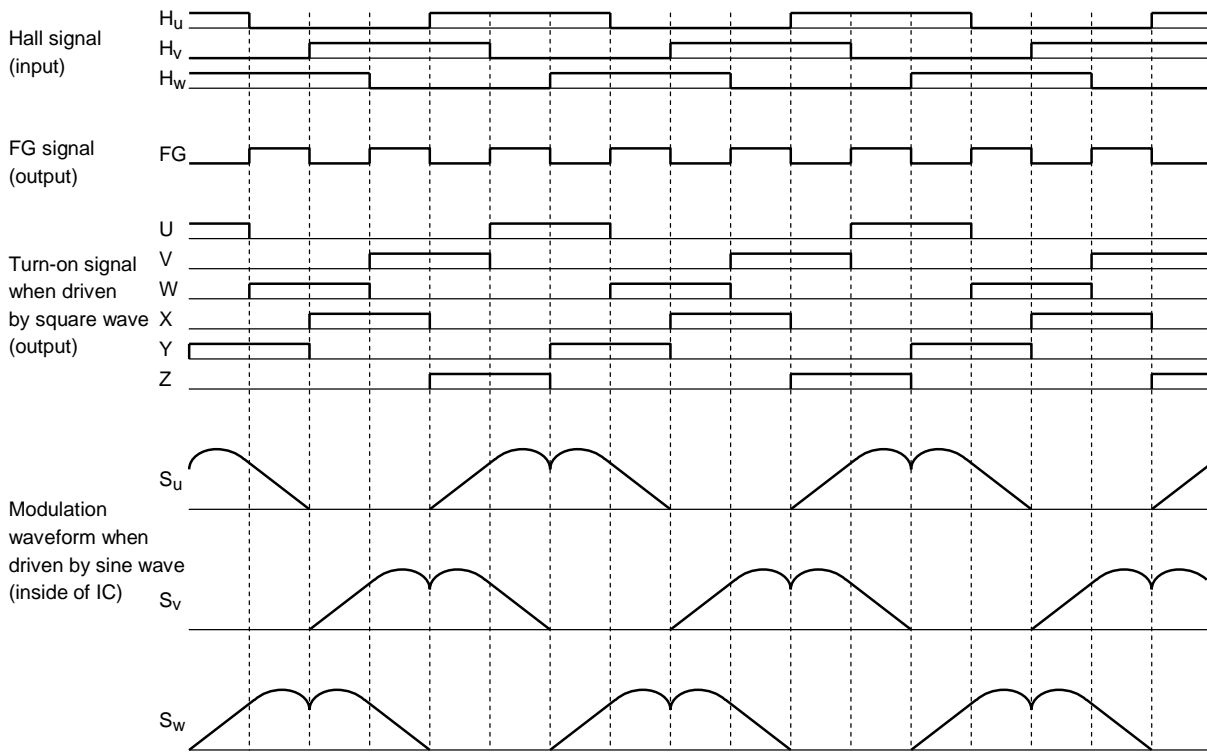
The modulation wave is brought into phase with every zero-cross point of the Hall signal.

The modulation wave is reset in synchronization with the rising and falling edges of the Hall signal at every electrical angle of 60°. Thus, when the Hall device is not placed in the correct position or during accelerating or decelerating, the modulation waveform is not continuous at every reset.

Timing Charts



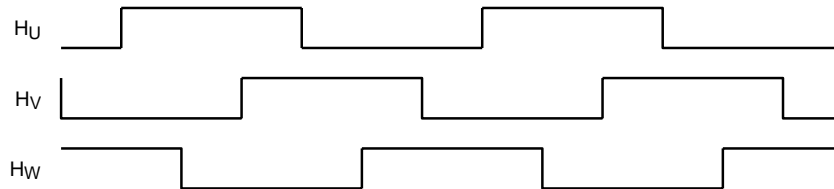
Forward



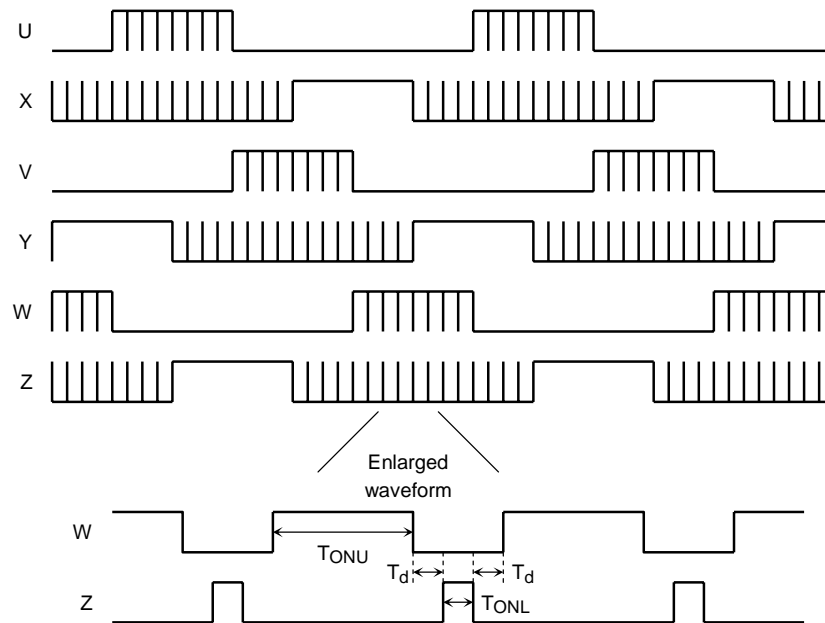
Reverse

Operating Waveform When Driven by Square Wave (CW/CCW = Low, OS = High)

Hall signal



Output waveform



To stabilize the bootstrap voltage, the lower outputs (X, Y, and Z) are always turned on at the carrier cycle even during off time. At that time, the upper outputs (U, V, and W) are assigned dead time and turned off at the timing when the lower outputs are turned on. (T_d varies with input V_e .)

$$\text{Carrier cycle} = f_{osc}/252 \text{ (Hz)}$$

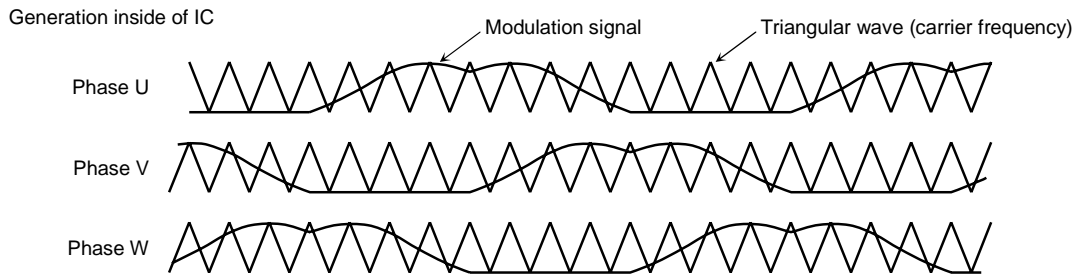
$$\text{Dead time: } T_d = 16/f_{osc} \text{ (s) (when } V_e = 4.6 \text{ V or more)}$$

$$TONL = \text{carrier cycle} \times 8\% \text{ (s) (uniform regardless of } V_e \text{ input)}$$

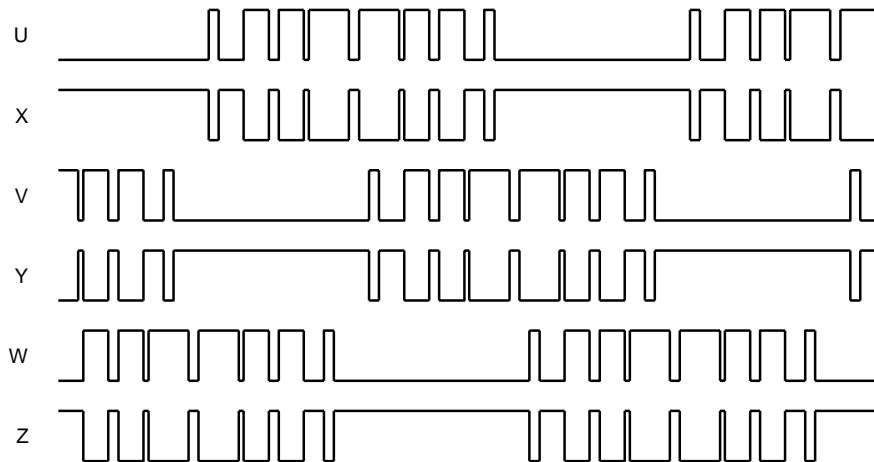
When the motor is driven by a square wave, acceleration or deceleration is determined by voltage V_e . The motor accelerates or decelerates according to the On duty of $TONU$. (See the diagram for output On duty on page 11.)

Note: The motor is driven by a square wave if REV = High, i.e., if the Hall signals at start-up are 5 Hz ($f_{osc} = 4 \text{ MHz}$) or lower and the motor is rotating in the reverse direction to that of the TB6551F/FG setting.

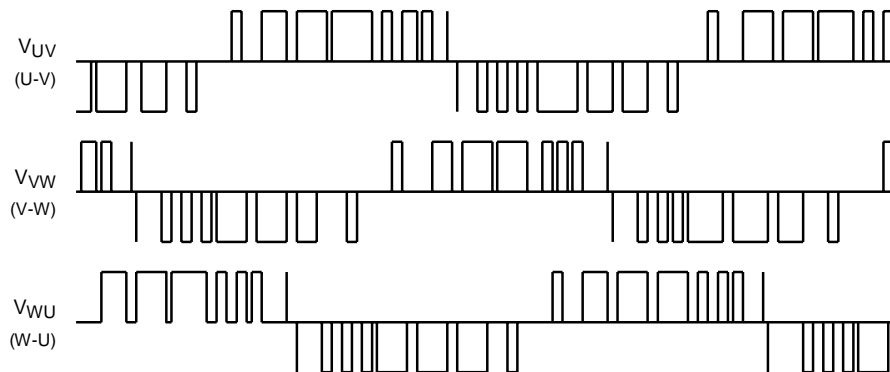
Operating Waveform When Driven by Sine-Wave PWM (CW/CCW = Low, OS = High)



Output waveform



Inter-line voltage

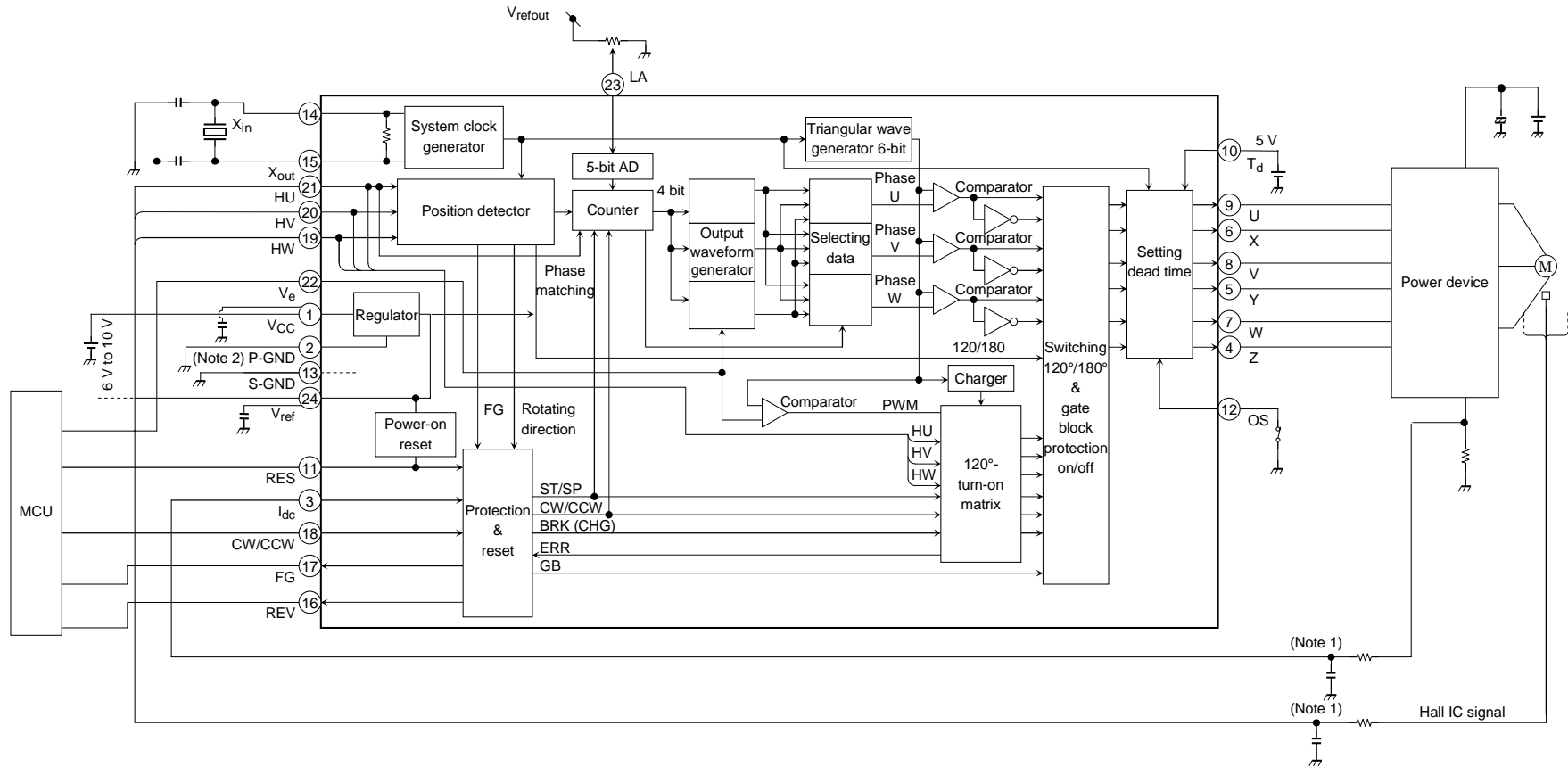


When the motor is driven by a sine wave, the motor is accelerated or decelerated according to the On duty of TONU when the amplitude of the modulation symbol changes by voltage V_e (see the diagram of output On duty on page 11):

$$\text{Triangular wave frequency} = \text{carrier frequency} = f_{osc}/252 \text{ (Hz)}.$$

Note: The motor is driven by a sine wave if REV = Low, i.e., if the Hall signals at start-up are 5 Hz ($f_{osc} = 4 \text{ MHz}$) or higher and the motor is rotating in the same direction as that of the TB6551F/FG setting.

Example of Application Circuit



Note 1: Connect as required to the ground to prevent IC malfunction due to noise.

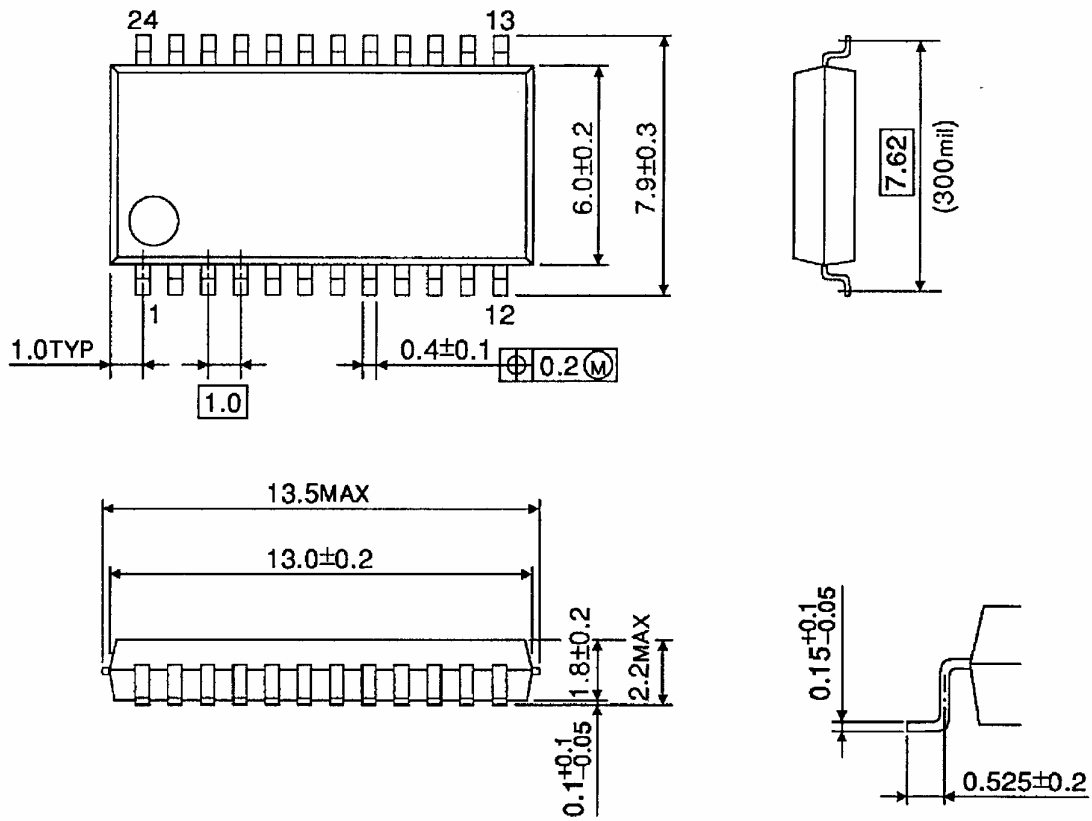
Note 2: Connect P-GND to signal ground on the application circuit.

Note 3: Utmost care is necessary in the design of the output, V_{CC} , V_M , and GND lines since the IC may be destroyed by short-circuiting between outputs, air contamination faults, or faults due to improper grounding, or by short-circuiting between contiguous pins.

Package Dimensions

SSOP24-P-300-1.00

Unit : mm



Weight: 0.33 g (typ.)

Notes on Contents**1. Block Diagrams**

Some of the functional blocks, circuits, or constants in the block diagram may be omitted or simplified for explanatory purposes.

2. Equivalent Circuits

The equivalent circuit diagrams may be simplified or some parts of them may be omitted for explanatory purposes.

3. Timing Charts

Timing charts may be simplified for explanatory purposes.

4. Application Circuits

The application circuits shown in this document are provided for reference purposes only. Thorough evaluation is required, especially at the mass production design stage.

Toshiba does not grant any license to any industrial property rights by providing these examples of application circuits.

5. Test Circuits

Components in the test circuits are used only to obtain and confirm the device characteristics. These components and circuits are not guaranteed to prevent malfunction or failure from occurring in the application equipment.

IC Usage Considerations**Notes on handling of ICs**

[1] The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded, even for a moment. Do not exceed any of these ratings.

Exceeding the rating(s) may cause the device breakdown, damage or deterioration, and may result injury by explosion or combustion.

[2] Do not insert devices in the wrong orientation or incorrectly.

Make sure that the positive and negative terminals of power supplies are connected properly.

Otherwise, the current or power consumption may exceed the absolute maximum rating, and exceeding the rating(s) may cause the device breakdown, damage or deterioration, and may result injury by explosion or combustion.

In addition, do not use any device that is applied the current with inserting in the wrong orientation or incorrectly even just one time.

RESTRICTIONS ON PRODUCT USE

070122EBA_R6

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